

HETEROJUNCTION BI-POLAR TRANSISTORS

Part Number (RF Specifications @ 2 GHz)	Freq. Range (MHz)	SS Gain (dB)	Pout @ -1dB (dBm)	OIP3 (dBm)	Noise Figure (dB)	Return Loss		Supply Voltage (VDC)	Ic (mA)	Package
						INPUT (-dB)	OUTPUT (-dB)			
HBT GAIN BLOCKS										
GSA-504-12	0.01 ~ 4000	20	+15	+27	3.6	15	15	+5.0	48	12
GSA-603-12	0.01 ~ 3500	18	+16	+28	3.8	15	15	+6.0	48	12
GSA-606-12	0.01 ~ 7000	15	+15	+28	4.0	15	15	+6.0	48	12
GSA-804-89	0.01 ~ 4000	12.5	+20	+40	4.5	15	15	+8.0	95	SOT89
GSA-804-12	0.01 ~ 4000	12.5	+20	+40	4.5	15	15	+8.0	95	12
HBT POWER DEVICES										
GSP-7427-89	0.01 ~ 6000	16*	+26*	+45*	6.0*	15*	7*	+7.0	130	SOT89
GSP-7430-30	0.01 ~ 6000	17*	+30*	+51*	7.0*	15*	7*	+7.0	360	30
GSP-7433-30	0.01 ~ 6000	16*	+34*	+53*	7.0*	15*	7*	+7.0	700	30
GSP-7436-40	0.01 ~ 6000	12*	+36*	+55*	7.0*	15*	6*	+7.0	1400	40

HETEROSTRUCTURE FIELD-EFFECT TRANSISTORS

Part Number (RF Specifications @ 2 GHz)	Freq. Range (MHz)	SS Gain (dB)	Pout @ -1dB (dBm)	OIP3 (dBm)	Noise Figure (dB)	Return Loss		Supply Voltage (VDC)	Ic (mA)	Package
						INPUT (-dB)	OUTPUT (-dB)			
HFET GAIN BLOCKS										
GSF-504-89	0.01 ~ 4000	13	+24	+40	3.3	6	14	+5.0	150	SOT89
GSF-504-12	0.01 ~ 4000	13.5	+24	+40	3.0	7	15	+5.0	150	12
HFET MEDIUM POWER DEVICES										
GSH-904-89	0.01 ~ 4000	13	+27*	+41*	3.5	15*	15*	+9.0	100	SOT89
GSH-912-12	0.01 ~ 12000	13	+27*	+41*	3.5	15*	15*	+9.0	100	12

Devices marked with (*) require external matching circuits

Also available in die form as a GSA-xxx-00, GSF-xxx-00, GSH-xxx-00, or GSP-xxx-00. See Short Form Catalog for performance details.